



AH3765Q

HIGH-VOLTAGE, MEDIUM-SENSITIVITY AUTOMOTIVE HALL-EFFECT LATCH

Description

The AH3765Q is an AEC-Q100 qualified high-voltage, mediumsensitivity Hall-Effect latch IC designed for brushless DC-motor commutation, speed measurement, angular or linear encoders and position sensors in automotive applications. To support wide range of demanding applications, the design is optimized to operate over the supply range of 3.0V to 28V. With chopper stabilized architecture and an internal bandgap regulator to provide temperature compensated supply for internal circuits, the AH3765Q provides a reliable solution over the whole operating range. For robustness and protection, the device has a reverse blocking diode with a Zener clamp on the supply. The output has an overcurrent limit and a Zener clamp.

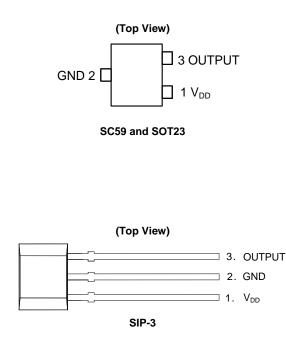
The single, open-drain output can be switched on with South pole of sufficient strength and switched off with North pole of sufficient strength. When the magnetic flux density (B) perpendicular to the package is larger than the operate point (B_{op}) the output is switched on (pulled low). The output is held latched until magnetic flux density reverses and becomes lower than the release point (B_{rp}).

The magnetic operating and release polarity is opposite for SOT23 and SC59 packages. SOT23 and SIP-3 packages will require South pole to the part marking side to operate while SC59 will require South pole to the non-part-marking side.

Features

- Bipolar Latch Operation (South Pole: On, North Pole: off)
- High Sensitivity: Bop and Brp of +70G and -70G Typical
- Single Open-Drain Output with Overcurrent Limit
- 3.0V to 28V Operating Voltage Range
- Chopper Stabilized Design Provides
 - Superior Temperature Stability
 - Minimal Switch Point Drift
 - Enhanced Immunity to Stress
- Good RF Noise Immunity
- Reverse Blocking Diode
- Zener Clamp on Supply and Output Pins
- -40°C to +150°C Operating Temperature
- ESD: HBM >8kV, CDM: >2kV
- AEC-Q100 Grade 0 Qualified
- Industry Standard SC59, SOT23 and SIP-3 Packages
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



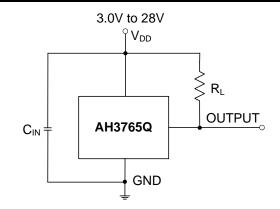
Applications

- Brushless DC-Motor Commutation
- Revolution Per Minute (RPM) Measurement
- · Angular and Linear Encoder and Position Sensing and Indexing
- Flow Meters
- Contactless Commutation, Speed Measurement and Angular Position Sensing/Indexing in Automotive Applications

- Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 - 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Typical Applications Circuit



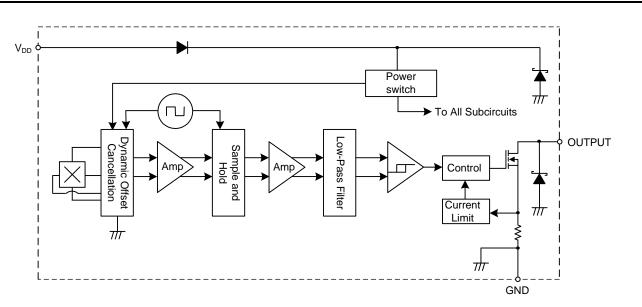
Note: 4. C_{IN} is for power stabilization and to strengthen the noise immunity, the recommended capacitance is 10nF ~ 100nF. RL is the pull-up resistor.

Pin Descriptions

Package: SC59, SOT23 and SIP-3

Pin Number	Pin Name	Function			
1	V _{DD}	Power Supply Input			
2	GND	Ground			
3	OUTPUT	Output Pin			

Functional Block Diagram





Absolute Maximum Ratings (Notes 5 & 6) (@T_A = +25°C, unless otherwise specified.)

Symbol	Characteristic		Value	Unit	
V _{DD}	Supply Voltage (Note 6)		32	V	
V _{DDR}	Reverse Supply Voltage (Note 6)		-32	V	
V _{OUT_MAX}	Output Off Voltage (Note 6)		32	V	
IOUT	Continuous Output Current		60	mA	
IOUT_R	Reverse Output Current		-50	mA	
В	Magnetic Flux Density		Unlimited		
D-	Package Power Dissipation	SIP-3	550	mW	
PD	Fackage Fower Dissipation	SC59 and SOT23	230	TIIVV	
Ts	Storage Temperature Range		-65 to +165	°C	
TJ	Maximum Junction Temperature		+150	°C	
ESD HBM	Electros Static Discharge Withstand - Human Body Model (HMI	3)	8	kV	
ESD MM	Electros Static Discharge Withstand - Machine Model (MM)		800	V	
ESD CDM	Electros Static Discharge Withstand - Charged Device Model (C	CDM)	2	kV	

Notes: 5. Stresses greater than the 'Absolute Maximum Ratings' specified above may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.

6. The absolute maximum V_{DD} of 32V is a transient stress rating and is not meant as a functional operating condition. It is not recommended to operate the device at the absolute maximum rated conditions for any period of time.

Recommended Operating Conditions (@T_A = -40°C to +150°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Rating	Unit
V _{DD}	Supply Voltage	Operating	3.0 to 28	V
TA	Operating Temperature Range	Operating	-40 to +150	°C

Electrical Characteristics (Notes 7 & 8) (@TA = -40°C to +150°C, VDD = 3V to 28V, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Vout_on	Output On Voltage	$I_{OUT} = 20 \text{mA}, \text{B} > B_{op}$	-	0.2	0.4	V
I _{LKG}	Output Leakage Current (when output is off)	$V_{OUT} = 28V, B < B_{rp}, Output off$	-	<0.1	10	μA
I _{DD}	Supply Current	Output open, T _A = +25°C	-	3	3.5	mA
		Output open, $T_A = -40^{\circ}C$ to +150°C	-	-	4	mA
		V _{DD} = -18V, T _A = +25°C	-	0.6	-	μA
	Roverse Supply Current	$V_{DD} = -18V, T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	-	0.6	1,500	μA
I _{DD_R}	Reverse Supply Current	$V_{DD} = -28V, T_A = +25^{\circ}C$	-	1.6	- 2,500	μA
		$V_{DD} = -28V, T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	-	1.6	2,500	μA
tp_on	Device Power-On Time (start-up time)	$V_{DD} \ge 3V, B \ge B_{op}$ (Note 7)	-	10		μs
f _c	Chopping Frequency	V _{DD} >= 3V	-	800	-	kHz
t _d	Response Time Delay (time from magnetic threshold reached to the start of the output rise or fall)	(Note 9)	-	3.75	-	μs
tr	Output Rising Time (external pull-up resistor R∟ and load capacitance dependent)	$R_L = 1k\Omega, C_L = 20pF$	-	0.2	1	μs
t _f	Output Falling Time (Internal switch resistance and load capacitance dependent)	$R_L = 1k\Omega, C_L = 20pF$	-	0.1	1	μs
IOCL	Output Current Limit	B > B _{op} , (Note 10)	30	-	55	mA
Vz	Zener Clamp Voltage	$I_{DD} = 5 \text{mA}$	28	-	-	V

Notes:

7. When power is initially turned on, Vpp must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the start-up time of 10µs typical from the operating voltage reaching 3V.

8. Typical values are defined at T_A = +25°C, V_{DD} = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.

9. Guaranteed by design, process control and characterization. Not tested in production.

10. The device will limit the output current IOUT to current limit of IOCL.



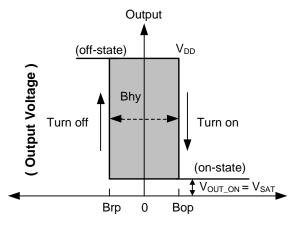
Magnetic Characteristics (Notes 11 & 12) ($T_A = -40^{\circ}C$ to $+150^{\circ}C$, $V_{DD} = 3.0V$ to 28V, unless otherwise specified)

				(1mT=10 0	Gauss)
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Bops (South pole to part marking side for		$V_{DD} = 12V, T_A = +25^{\circ}C$	-	70	-	
SOT23 and SIP-3 packages; South pole to the non-part marking side for SC59 package. See diagram below)	Operation Point	$T_{A} = -40^{\circ}C \text{ to } +150^{\circ}C$	50	70	90	
B _{rps} (North pole to part marking side for		$V_{DD} = 12V, T_A = +25^{\circ}C$	-	-70	-	Gauss
SOT23 and SIP-3 packages; North pole to the non-part marking side for SC59 package. See diagram below)	Release Point	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	-90	-70	-50	Gauss
	Hysteresis (Note 13)	$V_{DD} = 12V, T_A = +25^{\circ}C$	-	140	-	
Bhy (Bopx - Brpx)	Hystelesis (Note 13)	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	100	140	180	

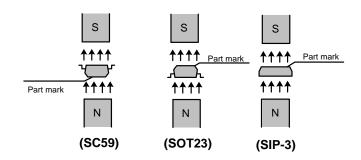
Notes: 11. When power is initially turned on, V_{DD} must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the start-up time of 10µs typical from the operating voltage reaching 3V.

12. Typical values are defined at T_A = +25°C, V_{DD} = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.

13. Maximum and minimum hysteresis is guaranteed by design, process control and characterization.



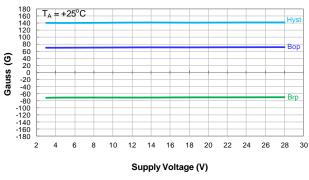
(Magnetic Flux Density B)



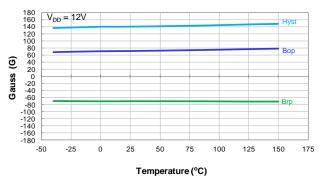


Typical Operating Characteristics

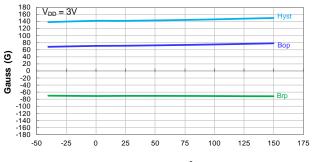
Output Switch Operate and Release Points (Magnetic Thresholds) – Bop and Brp



Switch Points Bop and Brp vs Supply Voltage

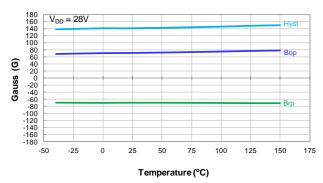


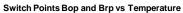
Switch Points Bop and Brp vs Temperature

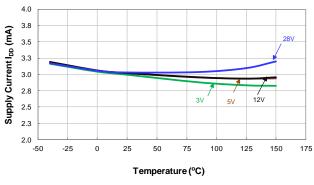


Temperature (°C)



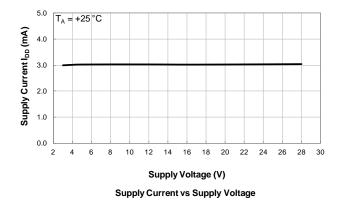






Supply Current vs Temperature

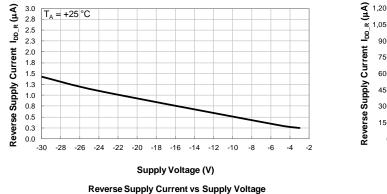
Supply Current

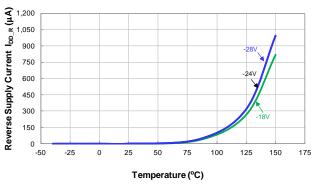




Typical Operating Characteristics (cont.)

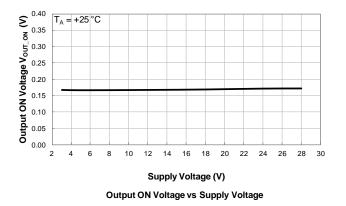
Reverse Supply Current





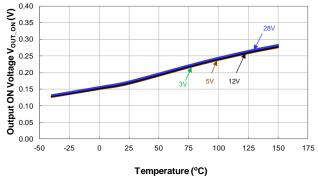


Output Switch On Voltage

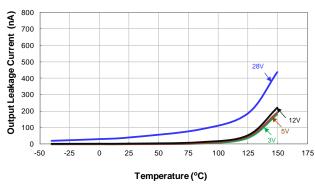


Supply Voltage (V)

Output Leakage Current vs Supply Voltage



Output ON Voltage vs Temperature



Output Leakage Current vs Temperature

Output Switch Leakage Current

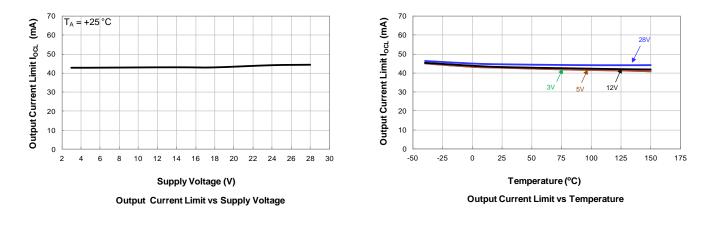
T_A = +25 °C

Output Leakage Current I_{LK6} (nA)



Typical Operating Characteristics (cont.)

Output Current Limit

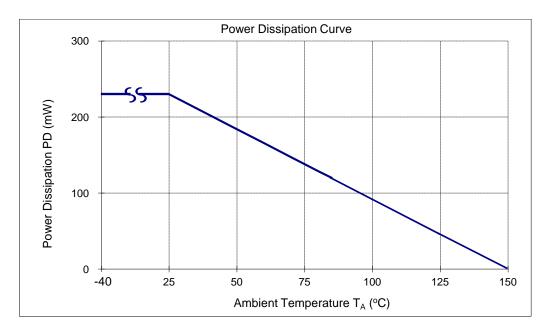




Thermal Performance Characteristics

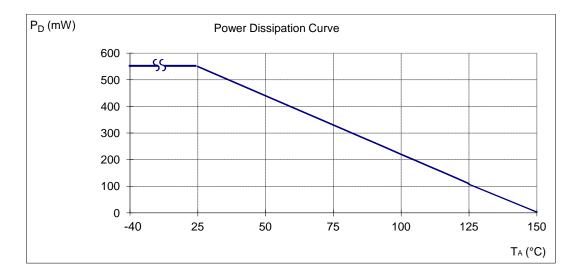
(1) Package type: SC59 and SOT23

T _A (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P _D (mW	230	184	166	147	129	120	110	92	83	74	55	46	37	18	0



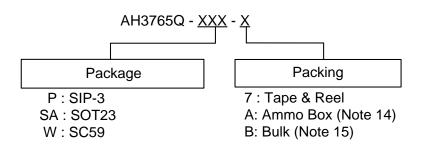
(2) Package type: SIP-3

T _A (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P _D (mW)	550	440	396	362	308	286	264	220	198	176	132	110	88	44	0





Ordering Information

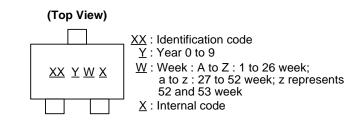


	Baakaga		В	Bulk	7" Tape an	7" Tape and Reel		Ammo Box	
Part Number	Package Code	Packaging	Quantity	Part Number Suffix	Quantity	Part Number Suffix	Quantity	Part Number Suffix	
AH3765Q-P-A	Р	SIP-3	NA	NA	NA	NA	4,000/Box	-A	
AH3765Q-P-B	Р	SIP-3	1,000	-B	NA	NA	NA	NA	
AH3765Q-SA-7	SA	SOT23	NA	NA	3,000/Tape & Reel	-7	NA	NA	
AH3765Q-W-7	W	SC59	NA	NA	3,000/Tape & Reel	-7	NA	NA	

Notes:14. Ammo Box is for SIP-3 Spread Lead.15. Bulk is for SIP-3 Straight Lead.

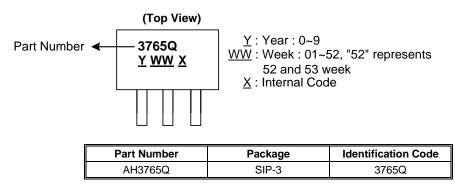
Marking Information

(1) Package Type: SC59 and SOT23



Part Number	Package	Identification Code
AH3765Q	SC59	YP
AH3765Q	SOT23	WP

(2) Package Type: SIP-3

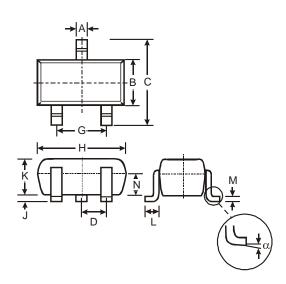




Package Outline Dimensions (All dimensions in mm.)

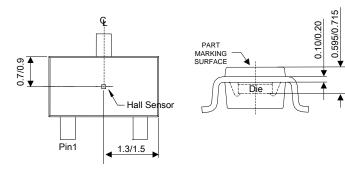
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

(1) Package Type: SC59



	SC	:59	
Dim	Min	Max	Тур
Α	0.35	0.50	0.38
В	1.50	1.70	1.60
C	2.70	3.00	2.80
D	-	-	0.95
G	-	-	1.90
H	2.90	3.10	3.00
J	0.013	0.10	0.05
ĸ	1.00	1.30	1.10
L	0.35	0.55	0.40
Μ	0.10	0.20	0.15
N	0.70	0.80	0.75
α	0°	8°	-
All	Dimens	ions in	mm

Min/Max



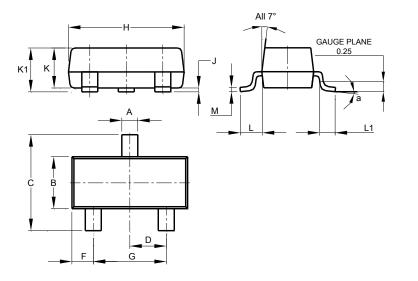
Sensor Location



Package Outline Dimensions (cont.) (All dimensions in mm.)

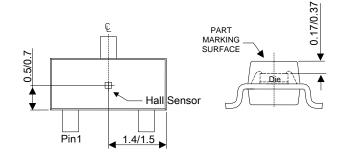
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

(2) Package Type: SOT23



	SO	T23	
Dim	Min	Max	Тур
Α	0.37	0.51	0.40
В	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
Н	2.80	3.00	2.90
J	0.013	0.10	0.05
К	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
М	0.085	0.150	0.110
а		8°	
All	Dimens	ions in	mm

Min/Max



Sensor Location - To be updated

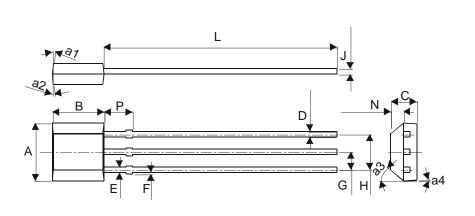


Package Outline Dimensions (cont.) (All dimensions in mm.)

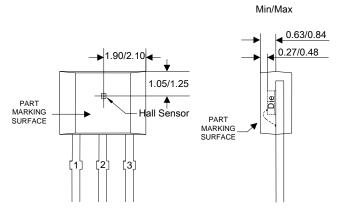
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

(3) Package Type: SIP-3 Bulk

Sensor location to be added



	SIP-3 (Bu	lk)		
Dim	Min	Max		
Α	3.9	4.3		
a1	5°	Тур		
a2	5°	Тур		
a3	45°	' Тур		
a4	3°	Тур		
В	2.8	3.2		
с	1.40	1.60		
D	0.33	0.432		
ш	0.40	0.508		
F	0	0.2		
G	1.24	1.30		
H	2.51	2.57		
J	0.35	0.43		
L	14.0	15.0		
N	0.63	0.84		
Р	1.55	-		
All Di	mension	s in mm		



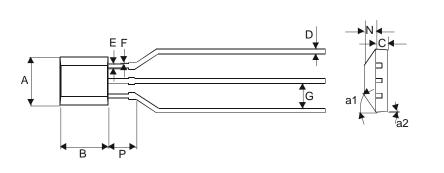
Sensor Location - To be updated



Package Outline Dimensions (cont.) (All dimensions in mm.)

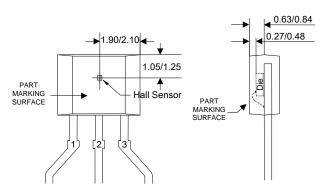
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

(4) Package Type: SIP-3 Ammo Pack



SIP-3 (Ammo Pack)		
Dim	Min	Max
Α	3.9	4.3
a1	45° Typ	
a2	3° Тур	
в	2.8	3.2
С	1.40	1.60
D	0.35	0.41
E	0.43	0.48
F	0	0.2
G	2.4	2.9
N	0.63	0.84
Р	1.55	-
All Dimensions in mm		





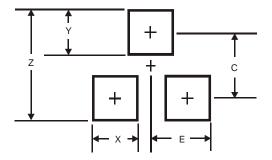
Sensor Location - To be updated



Suggested Pad Layout

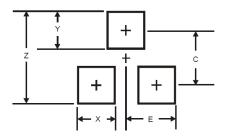
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

(1) Package Type: SC59



Dimensions	Value (in mm)
Z	3.4
Х	0.8
Y	1.0
С	2.4
E	1.35

(2) Package Type: SOT23



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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